

# 3.3V CMOS Static RAM 1 Meg (64K x 16-Bit)

## Features

- 64K x 16 advanced high-speed CMOS Static RAM
- Equal access and cycle times
   Commercial: 10/12/15/20ns
   Industrial: 10/12/15/20ns
  - Industrial: 10/12/15/20ns
- One Chip Select plus one Output Enable pin
  Bidirectional data inputs and outputs directly LVTTL-compatible
- Low power consumption via chip deselect
- Upper and Lower Byte Enable Pins
- Single 3.3V power supply
- Available in 44-pin Plastic SOJ, 44-pin TSOP, and 48-Ball Plastic FBGA packages
- Industrial temperature range (-40°C to +85°C) is available for selected speeds
- Green parts available, see ordering information

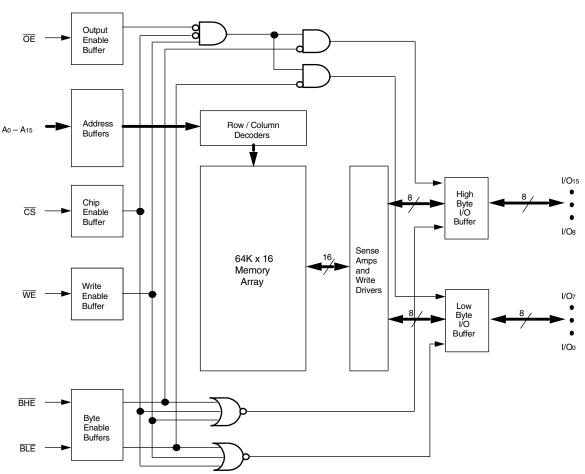
# Functional Block Diagram

# Description

The IDT71V016 is a 1,048,576-bit high-speed Static RAM organized as 64K x 16. It is fabricated using high-performance, high-reliability CMOS technology. This state-of-the-art technology, combined with innovative circuit design techniques, provides a cost-effective solution for high-speed memory needs.

The IDT71V016 has an output enable pin which operates as fast as 5ns, with address access times as fast as 10ns. All bidirectional inputs and outputs of the IDT71V016 are LVTTL compatible and operation is from a single 3.3V supply. Fully static asynchronous circuitry is used, requiring no clocks or refresh for operation.

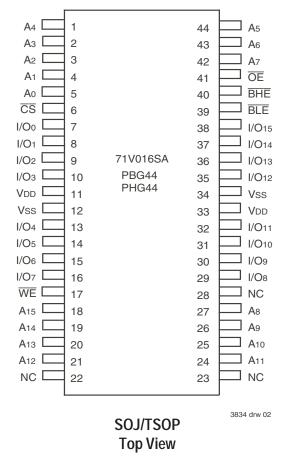
The IDT71V016 is packaged in a JEDEC standard 44-pin Plastic SOJ, a 44-pin TSOP Type II, and a 48-ball plastic 7 x 7 mm FBGA.





#### 71V016SA, 3.3V CMOS Static RAM 1 Meg (64K x 16-Bit)

# Pin Configurations - PBG44, PHG44<sup>(1)</sup>



#### NOTE:

1. This text does not indicate orientation of actual part-marking.

	1 2 3 4 5									
A	BLE	ŌĒ	Ao	A1	A2	NC				
В	I/O8	BHE	A3	A4	CS	I/Oo				
С	I/O9	I/O10	A5	A6	I/O1	I/O2				
D	Vss	I/O11	NC	A7	I/O3	Vdd				
E	Vdd	I/O12	NC	NC	I/O4	Vss				
F	I/O14	I/O13	A14	<b>A</b> 15	I/O5	I/O6				
G	I/O15	NC	<b>A</b> 12	A13	WE	I/O7				
Η	NC	A8	A۹	<b>A</b> 10	A11	NC				
		FBG	A (BF48,	, BFG48)	(1)	3834 tbl 02a				

**Commercial and Industrial Temperature Ranges** 

### NOTE:

1. This text does not indicate orientation of actual part-marking.

## **Pin Description**

A0 – A15	Address Inputs	Input
CS	Chip Select	Input
WE	Write Enable	Input
ŌĒ	Output Enable	Input
BHE	High Byte Enable	Input
BLE	Low Byte Enable	Input
I/O0 – I/O15	Data Input/Output	I/O
Vdd	3.3V Power	Power
Vss	Ground	Gnd

**Top View** 

3834 tbl 01

CS	ŌĒ	WE	BLE	BHE	<b>I/O</b> 0- <b>I/O</b> 7	<b>I/O8-I/O</b> 15	Function
Н	Х	Х	Х	Х	High-Z	High-Z	Deselected – Standby
L	L	Н	L	Н	DATAOUT	DATAout High-Z Low Byte Read	
L	L	Н	Н	L	High-Z	DATAOUT	High Byte Read
L	L	Н	L	L	DATAOUT	DATAOUT	Word Read
L	Х	L	L	L	DATAIN	DATAIN	Word Write
L	Х	L	L	Н	DATAIN	High-Z	Low Byte Write
L	Х	L	Н	L	High-Z	DATAIN	High Byte Write
L	Н	Н	Х	Х	High-Z	High-Z	Outputs Disabled
L	Х	Х	Н	Н	High-Z	High-Z	Outputs Disabled

NOTE:

1.  $H = V_{IH}, L = V_{IL}, X = Don't care.$ 

Truth Table<sup>(1)</sup>

3834 tbl 02

## \_\_\_\_\_



#### **Commercial and Industrial Temperature Ranges**

## Absolute Maximum Ratings<sup>(1)</sup>

Symbol	Rating	Value	Unit
Vdd	Supply Voltage Relative to Vss	-0.5 to +4.6	V
Vin, Vout	Terminal Voltage Relative to Vss	-0.5 to VDD+0.5	V
Tbias	Temperature Under Bias	-55 to +125	٥C
Tstg	Storage Temperature	-55 to +125	٥C
Рт	Power Dissipation	1.25	W
Iout	DC Output Current	50	mA
NOTE.			3834 tbl 03

#### NOTE:

1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

# Capacitance

#### $(TA = +25^{\circ}C, f = 1.0MHz, SOJ package)$

	· · · · · · · · · · · · · · · · · · ·							
Symbol	Parameter <sup>(1)</sup>	Conditions Max		Unit				
Cin	Input Capacitance	VIN = 3dV	6	pF				
Cı/o	I/O Capacitance	Vout = 3dV	7	pF				
NOTE: 3834 tbl 0.								

NOTE:

1. This parameter is guaranteed by device characterization, but not production tested.

# DC Electrical Characteristics

(VDD = Min. to Max., Commercial and Industrial Temperature Ranges)

			IDT71V016SA		
Symbol	Parameter	Test Condition	Min.	Max.	Unit
lu	Input Leakage Current	VDD = Max., VIN = VSS to VDD		5	μA
Ilo	Output Leakage Current	$V_{DD} = Max., \overline{CS} = V_{IH}, V_{OUT} = V_{SS} to V_{DD}$		5	μA
Vol	Output Low Voltage	IOL = 8mA, VDD = Min.		0.4	V
Vон	Output High Voltage	IOH = -4mA, $VDD = Min$ .	2.4		V

3834 tbl 07

# DC Electrical Characteristics<sup>(1,2)</sup>

## (VDD = Min. to Max., VLC = 0.2V, VHC = VDD - 0.2V)

			71V016SA10 71V		71V01	71V016SA12		71V016SA15		71V016SA20	
Symbol	ol Parameter		Com'l	Ind'l	Com'l	Ind'l	Com'l	Ind'l	Com'l	Ind'l	Unit
lcc	Dynamic Operating Current	Max.	160	170	150	160	130	130	120	120	mA
	$\overline{CS} \le V_{LC}$ , Outputs Open, VDD = Max., f = fmax <sup>(3)</sup>	Typ. <sup>(4)</sup>	65	-	60		55		50		
ISB	Dynamic Standby Power Supply Current $\overline{CS} \ge V_{HC}$ , Outputs Open, VDD = Max., f = fMAX <sup>(3)</sup>		45	50	40	45	35	35	30	30	mA
ISB1	Full Standby Power Supply Current (static) $\overline{\text{CS}} \ge \text{VHc}$ , Outputs Open, VDD = Max., f = 0 <sup>(3)</sup>		10	10	10	10	10	10	10	10	mA

#### NOTES:

1. All values are maximum guaranteed values.

2. All inputs switch between 0.2V (Low) and VDD - 0.2V (High).

3. fmax = 1/trc (all address inputs are cycling at fmax); f = 0 means no address input lines are changing .

Typical values are based on characterization data for H step only measured at 3.3V, 25°C and with equal read and write cycles. 4.



# Recommended Operating Temperature and Supply Voltage

Grade Temperature		Vss	Vdd
Commercial	0°C to +70°C	0V	See Below
Industrial	-40°C to +85°C	0V	See Below

3834 tbl 04

3834 tbl 05

# Recommended DC Operating Conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit
Vdd <sup>(1)</sup>	Supply Voltage	3.15	3.3	3.6	۷
Vdd <sup>(2)</sup>	Supply Voltage	3.0	3.3	3.6	۷
Vss	Ground	0	0	0	۷
Vih	Input High Voltage	2.0		VDD+0.3(3)	۷
VIL	Input Low Voltage	-0.3(4)		0.8	٧

NOTES:

1. For 71V016SA10 only.

2. For all speed grades except 71V016SA10.

3. VIH (max.) = VDD+2V for pulse width less than 5ns, once per cycle.

4. VIL (min.) = -2V for pulse width less than 5ns, once per cycle.

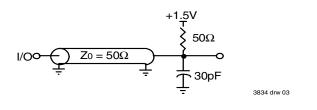
3834	tbl	80

# AC Test Conditions

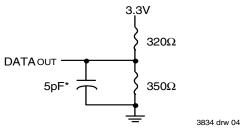
Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	1.5ns
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
AC Test Load	See Figure 1, 2 and 3

3834 tbl 09

# AC Test Loads







\*Including jig and scope capacitance.

Figure 2. AC Test Load (for tclz, tolz, tchz, tohz, tow, and twhz)

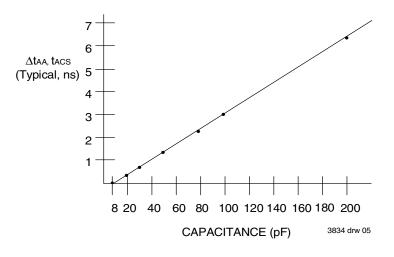


Figure 3. Output Capacitive Derating



## AC Electrical Characteristics (VDD = Min. to Max., Commercial and Industrial Temperature Ranges)

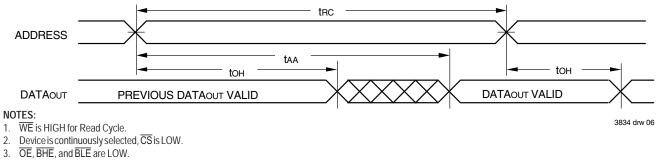
		71V01	16SA10	71V016SA12		71V016SA15		71V016SA20		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Unit
READ CYCL	E		•		•		•			
trc	Read Cycle Time	10		12		15		20		ns
taa	Address Access Time		10		12		15		20	ns
tacs	Chip Select Access Time		10		12		15		20	ns
tCLZ <sup>(1)</sup>	Chip Select Low to Output in Low-Z	4		4		5		5		ns
tснz <sup>(1)</sup>	Chip Select High to Output in High-Z		5		6	—	6		8	ns
toe	Output Enable Low to Output Valid		5		6	—	7		8	ns
tolz <sup>(1)</sup>	Output Enable Low to Output in Low-Z	0		0		0		0	_	ns
toHz <sup>(1)</sup>	Output Enable High to Output in High-Z		5		6		6		8	ns
toн	Output Hold from Address Change	4	_	4	_	4	_	4	_	ns
tBE	Byte Enable Low to Output Valid	_	5	_	6	_	7		8	ns
tBLZ <sup>(1)</sup>	Byte Enable Low to Output in Low-Z	0		0		0		0		ns
tвнz <sup>(1)</sup>	Byte Enable High to Output in High-Z		5		6	_	6		8	ns
WRITE CYC	LE									-
twc	Write Cycle Time	10		12	—	15		20	—	ns
taw	Address Valid to End of Write	7		8		10		12		ns
tcw	Chip Select Low to End of Write	7		8	—	10		12	—	ns
tøw	Byte Enable Low to End of Write	7		8	—	10		12	—	ns
tas	Address Set-up Time	0		0	—	0		0	—	ns
twr	Address Hold from End of Write	0		0	—	0	—	0	—	ns
twp	Write Pulse Width	7	—	8	—	10	—	12	—	ns
tow	Data Valid to End of Write	5		6	—	7		9	—	ns
tDH	Data Hold Time	0		0		0		0		ns
tow <sup>(1)</sup>	Write Enable High to Output in Low-Z	3	—	3	—	3		3	—	ns
twнz <sup>(1)</sup>	Write Enable Low to Output in High-Z		5		6	_	6		8	ns

NOTE:

1. This parameter is guaranteed with the AC Load (Figure 2) by device characterization, but is not production tested.

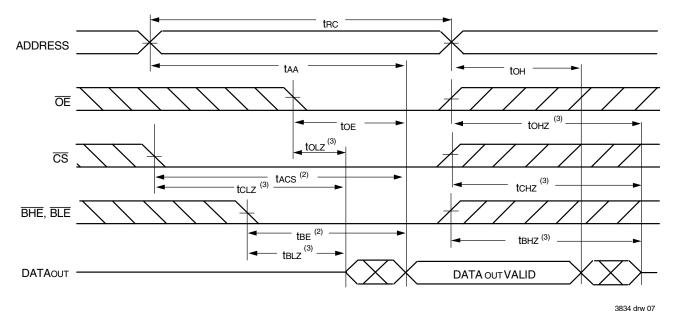
3834 tbl 10

# Timing Waveform of Read Cycle No. 1<sup>(1,2,3)</sup>





Timing Waveform of Read Cycle No. 2<sup>(1)</sup>



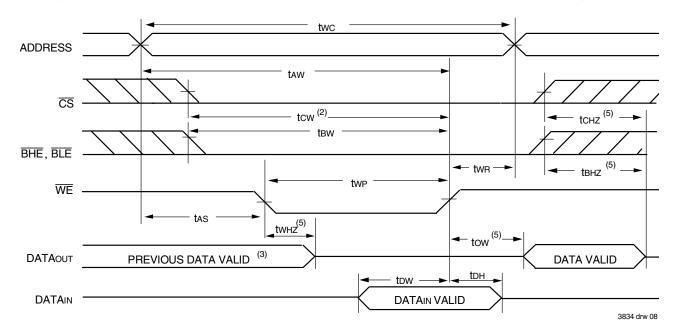
NOTES:

1. WE is HIGH for Read Cycle.

2. Address must be valid prior to or coincident with the later of CS, BHE, or BLE transition LOW; otherwise taa is the limiting parameter.

3. Transition is measured ±200mV from steady state.

# Timing Waveform of Write Cycle No. 1 (WE Controlled Timing)<sup>(1,2,4)</sup>



### NOTES:

1. A write occurs during the overlap of a LOW CS, LOW BHE or BLE, and a LOW WE.

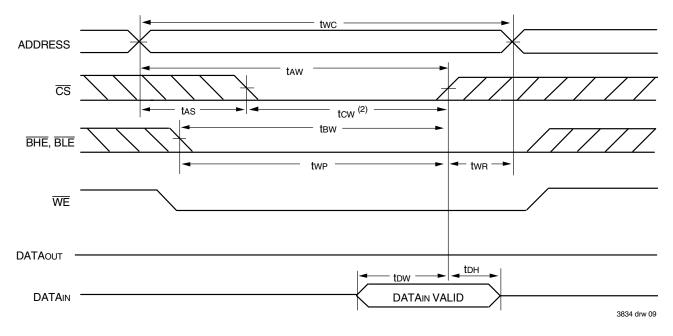
 OE is continuously HIGH. If during a WE controlled write cycle OE is LOW, twp must be greater than or equal to twHz + tow to allow the I/O drivers to turn off and data to be placed on the bus for the required tow. If OE is HIGH during a WE controlled write cycle, this requirement does not apply and the minimum write pulse is as short as the specified twp.
 During this period, I/O pins are in the output state, and input signals must not be applied.

4. If the CS LOW or BHE and BLE LOW transition occurs simultaneously with or after the WE LOW transition, the outputs remain in a high-impedance state.

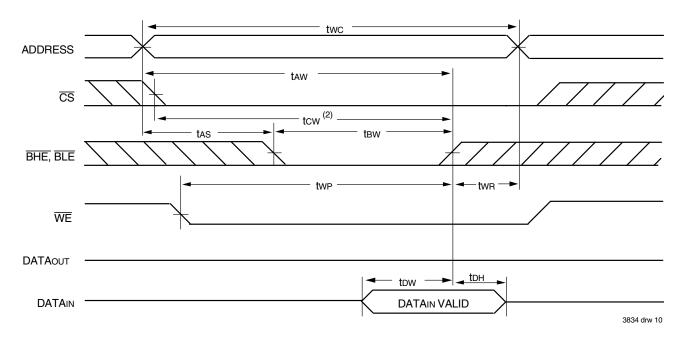
5. Transition is measured  $\pm 200$  mV from steady state.



Timing Waveform of Write Cycle No. 2 (CS Controlled Timing)<sup>(1,4)</sup>



Timing Waveform of Write Cycle No. 3 (BHE, BLE Controlled Timing)<sup>(1,4)</sup>



#### NOTES:

1. A write occurs during the overlap of a LOW  $\overline{CS}$ , LOW  $\overline{BHE}$  or  $\overline{BLE}$ , and a LOW  $\overline{WE}$ .

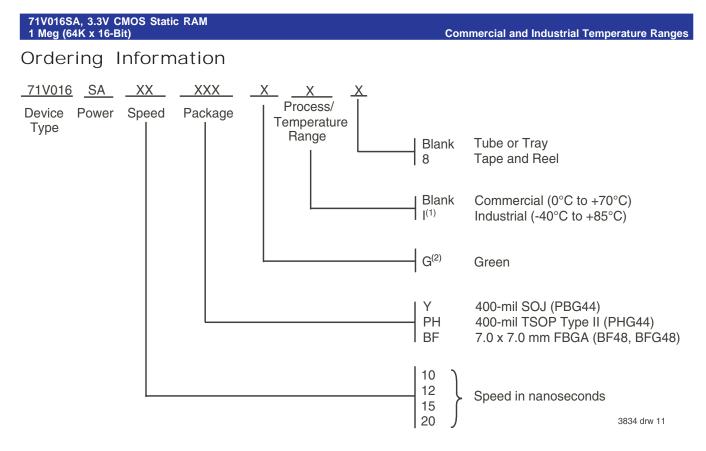
2. OE is continuously HIGH. If during a WE controlled write cycle OE is LOW, twp must be greater than or equal to twHz + tow to allow the I/O drivers to turn off and data to be placed on the bus for the required tow. If OE is HIGH during a WE controlled write cycle, this requirement does not apply and the minimum write pulse is as short as the specified twp.

3. During this period, I/O pins are in the output state, and input signals must not be applied.

4. If the  $\overline{CS}$  LOW or  $\overline{BHE}$  and  $\overline{BLE}$  LOW transition occurs simultaneously with or after the  $\overline{WE}$  LOW transition, the outputs remain in a high-impedance state.

5. Transition is measured  $\pm 200 \text{mV}$  from steady state.





#### NOTE:

1. Contact your local sales office for industrial temp. range for other speeds, packages and powers.

2. Green parts available. For specific speeds, packages and powers contact your local sales office.

Note that information regarding recently obsoleted parts are included in this datasheet for customer convenience.



# Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
10	71V016SA10BF	BF48	CABGA	С
	71V016SA10BF8	BF48	CABGA	С
	71V016SA10BFG	BFG48	CABGA	С
	71V016SA10BFG8	BFG48	CABGA	С
	71V016SA10BFGI	BFG48	CABGA	Ι
	71V016SA10BFGI8	BFG48	CABGA	I
	71V016SA10PHG	PHG44	TSOP	С
	71V016SA10PHG8	PHG44	TSOP	С
	71V016SA10PHGI	PHG44	TSOP	I
	71V016SA10PHGI8	PHG44	TSOP	I
	71V016SA10YG	PBG44	SOJ	С
	71V016SA10YG8	PBG44	SOJ	С
12	71V016SA12BF	BF48	CABGA	С
	71V016SA12BF8	BF48	CABGA	С
	71V016SA12BFG	BFG48	CABGA	С
	71V016SA12BFG8	BFG48	CABGA	С
	71V016SA12BFGI	BFG48	CABGA	I
	71V016SA12BFGI8	BFG48	CABGA	I
	71V016SA12BFI	BF48	CABGA	Ι
	71V016SA12BFI8	BF48	CABGA	I
	71V016SA12PHG	PHG44	TSOP	С
	71V016SA12PHG8	PHG44	TSOP	С
	71V016SA12PHGI	PHG44	TSOP	I
	71V016SA12PHGI8	PHG44	TSOP	I
	71V016SA12YG	PBG44	SOJ	С
	71V016SA12YG8	PBG44	SOJ	С
	71V016SA12YGI	PBG44	SOJ	I
	71V016SA12YGI8	PBG44	SOJ	I

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
15	71V016SA15BF	BF48	CABGA	С
	71V016SA15BF8	BF48	CABGA	С
	71V016SA15BFG	BFG48	CABGA	С
	71V016SA15BFG8	BFG48	CABGA	С
	71V016SA15BFGI	BFG48	CABGA	Ι
	71V016SA15BFGI8	BFG48	CABGA	Ι
	71V016SA15BFI	BF48	CABGA	Ι
	71V016SA15BFI8	BF48	CABGA	Ι
	71V016SA15PHG	PHG44	TSOP	С
	71V016SA15PHG8	PHG44	TSOP	С
	71V016SA15PHGI	PHG44	TSOP	Ι
	71V016SA15PHGI8	PHG44	TSOP	I
	71V016SA15YG	PBG44	SOJ	С
	71V016SA15YG8	PBG44	SOJ	С
	71V016SA15YGI	PBG44	SOJ	Ι
	71V016SA15YGI8	PBG44	SOJ	I
20	71V016SA20BF	BF48	CABGA	С
	71V016SA20BF8	BF48	CABGA	С
	71V016SA20BFG	BFG48	CABGA	С
	71V016SA20BFG8	BFG48	CABGA	С
	71V016SA20BFGI	BFG48	CABGA	Ι
	71V016SA20BFGI8	BFG48	CABGA	Ι
	71V016SA20BFI	BF48	CABGA	Ι
	71V016SA20BFI8	BF48	CABGA	Ι
	71V016SA20PHG	PHG44	TSOP	С
	71V016SA20PHG8	PHG44	TSOP	С
	71V016SA20PHGI	PHG44	TSOP	I
	71V016SA20PHGI8	PHG44	TSOP	I
	71V016SA20YG	PBG44	SOJ	С
	71V016SA20YG8	PBG44	SOJ	С
	71V016SA20YGI	PBG44	SOJ	I

PBG44

SOJ

T

71V016SA20YGI8

## **Commercial and Industrial Temperature Ranges**



# Datasheet Document History

		5
01/07/00		Updated to new format
	Pg. 1, 3, 5, 8	Added Industrial Temperature range offerings
	Pg. 2	Numbered I/Os and address pins on FBGA Top View
	Pg. 6	Revised footnotes on Write Cycle No. 1 diagram
	Pg. 7	Revised footnotes on Write Cycle No. 2 and No. 3 diagrams
	Pg. 9	Added Datasheet Document History
08/30/00	Pg. 3	Tighten Icc and IsB.
	Pg. 5	Tighten tclz, tchz, tohz, tbhz and twhz
08/22/01	Pg. 8	Removed footnote "available in 15ns and 20ns only"
06/20/02	Pg. 8	Added tape and reel field to ordering information
01/30/04	Pg. 8	Added "Restricted hazardous substance device" to ordering information.
09/27/06	Pg. 8	Corrected ordering information, changed position of I and G.
02/14/07	Pg.8	Added H step generation to data sheet ordering information.
06/26/07	Pg.3	Changed typical parameters for ICC, DC electrical characteristics table.
10/13/08	Pg.8	Removed "IDT" from orderable part number
10/11/11	Pg.1,8	Updated datasheet with removal of Obsolete HSA part number.
08/13/13	Pg.1,3,5,8	Added 10ns for Industrial Temperature range offerings.
06/23/20	Pg.1 - 9	Rebranded as Renesas datasheet
	Pg.1 & 8	Updated Industrial temp and Green availability
	Pg.2 & 8	Updated package codes
	Pg.9	Added Orderable Part Information tables
	-	



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